

MOSFETs Silicon N-channel MOS (U-MOSIV)

TK25E06K3

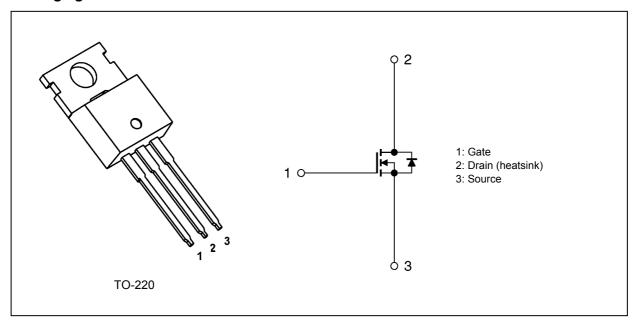
1. Applications

• Switching Voltage Regulators

2. Features

- (1) Low drain-source on-resistance: $R_{DS(ON)} = 14 \text{ m}\Omega$ (typ.)
- (2) High forward transfer admittance: $|Y_{fs}| = 50 \text{ S (typ.)}$
- (3) Low leakage current: $I_{DSS} = 10 \mu A \text{ (max)} \text{ (V}_{DS} = 60 \text{ V)}$
- (4) Enhancement mode: $V_{th} = 2.0$ to 4.0 V ($V_{DS} = 10$ V, $I_D = 1$ mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) (Ta = 25°C unless otherwise specified)

Chara	acteristics	Symbol	Rating	Unit	
Drain-source voltage			V_{DSS}	60	V
Drain-gate voltage	$(R_{GS} = 20 \text{ k}\Omega)$		V_{DGR}	60	
Gate-source voltage			V _{GSS}	±20	
Drain current (DC)		(Note 1)	I _D	25	Α
Drain current (pulsed)		(Note 1)	I _{DP}	75	
Power dissipation	(T _c = 25°C)		P_D	60	W
Single-pulse avalanche energy		(Note 2)	E _{AS}	54	mJ
Avalanche current			I _{AR}	25	Α
Repetitive avalanche energy		(Note 3)	E _{AR}	6	mJ
Channel temperature			T _{ch}	150	°C
Storage temperature			T _{stg}	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	R _{th(ch-c)}	2.08	°C/W
Channel-to-ambient thermal resistance	R _{th(ch-a)}	83.3	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 25 V, T_{ch} = 25°C (initial), L = 0.11 mH, R_G = 25 Ω , I_{AR} = 25 A

Note 3: Repetitive rating; pulse width limited by maximum channel temperature

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.



6. Electrical Characteristics

6.1. Static Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±1	μА
Drain cut-off current	I _{DSS}	V _{DS} = 60 V, V _{GS} = 0 V	_	_	10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	60	-	1	V
Drain-source breakdown voltage	V _{(BR)DSX}	I _D = 10 mA, V _{GS} = -20 V	35	_	_	
Gate threshold voltage	V_{th}	V _{DS} = 10 V, I _D = 1 mA	2.0	-	4.0	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 10 V, I _D = 13 A	_	14	18	mΩ
Forward transfer admittance	Y _{fs}	V _{DS} = 10 V, I _D = 13 A	25	50	_	S

6.2. Dynamic Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	_	1255	_	pF
Reverse transfer capacitance	C_{rss}		_	175		
Output capacitance	C _{oss}		_	235	_	
Switching time (rise time)	t _r	See Figure 6.2.1.	_	9	_	ns
Switching time (turn-on time)	t _{on}		_	21	_	
Switching time (fall time)	t _f		_	8	_	
Switching time (turn-off time)	t _{off}		_	29	_	

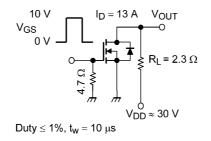


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} \approx 48 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 25 \text{ A}$	_	29	_	nC
Gate-source charge	Q_{gs}		_	16	_	
Gate-drain charge	Q_{gd}		-	13	_	

6.4. Source-Drain Characteristics (T_a = 25°C unless otherwise specified)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (DC)	(Note 4)	I _{DR}	_	_	_	25	Α
Reverse drain current (pulsed)	(Note 4)	I _{DRP}	_	_	_	75	
Diode forward voltage		V _{DSF}	I _{DR} = 25 A, V _{GS} = 0 V	_	_	-1.5	V
Reverse recovery time		t _{rr}	I _{DR} = 25 A, V _{GS} = 0 V	_	35	_	ns
Reverse recovery charge		Q _{rr}	-dI _{DR} /dt = 50 A/μs	_	17	_	nC

Note 4: Ensure that the channel temperature does not exceed 150°C.



7. Marking

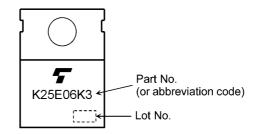


Fig. 7.1 Marking

Rev.1.0

8. Characteristics Curves (Note)

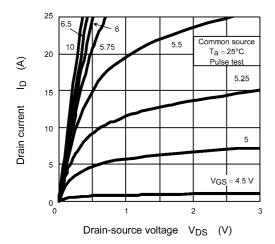


Fig. 8.1 $I_D - V_{DS}$

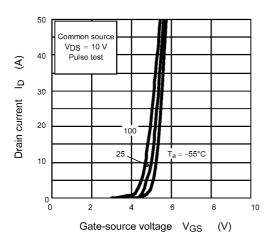


Fig. 8.3 I_D - V_{GS}

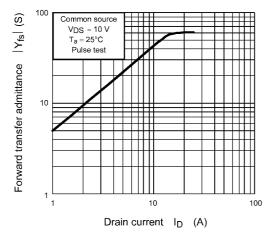


Fig. 8.5 |Y_{fs}| - I_D

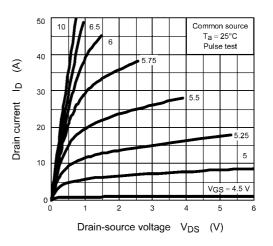


Fig. 8.2 $I_D - V_{DS}$

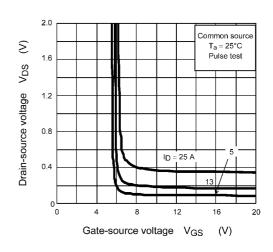


Fig. 8.4 V_{DS} - V_{GS}

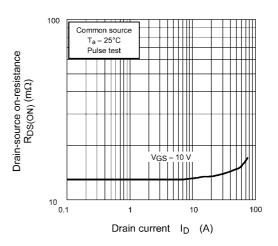


Fig. 8.6 R_{DS(ON)} - I_D

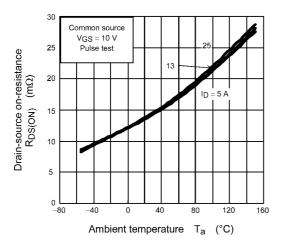


Fig. 8.7 R_{DS(ON)} - T_a

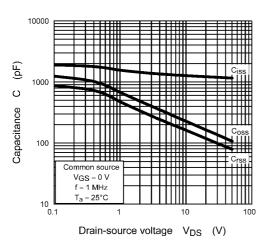


Fig. 8.9 Capacitance - V_{DS}

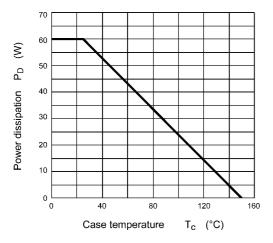


Fig. 8.11 P_D - T_c (Guaranteed Maximum)

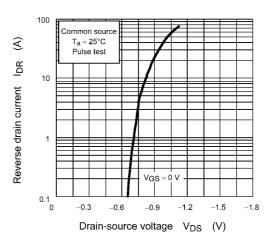


Fig. 8.8 IDR - VDS

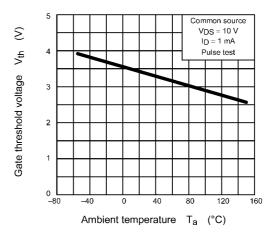


Fig. 8.10 V_{th} - T_a

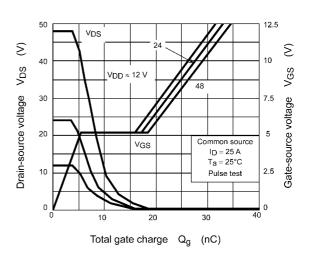


Fig. 8.12 Dynamic Input/Output Characteristics

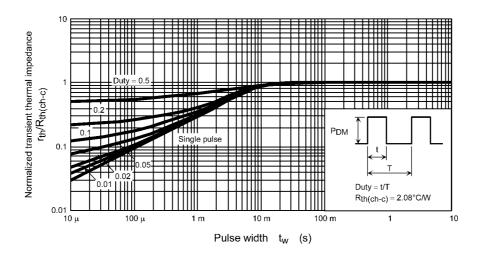


Fig. 8.13 r_{th}/R_{th(ch-c)} - t_w (Guaranteed Maximum)

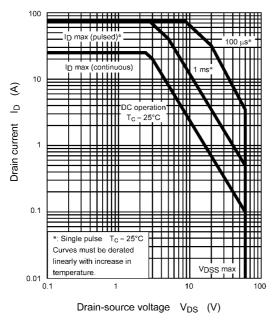


Fig. 8.14 Safe Operating Area (Guaranteed Maximum)

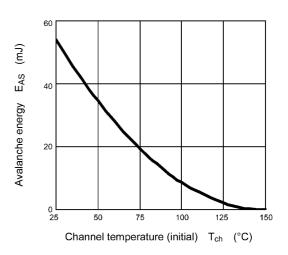


Fig. 8.15 E_{AS} - T_{ch} (Guaranteed Maximum)

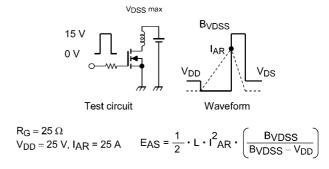


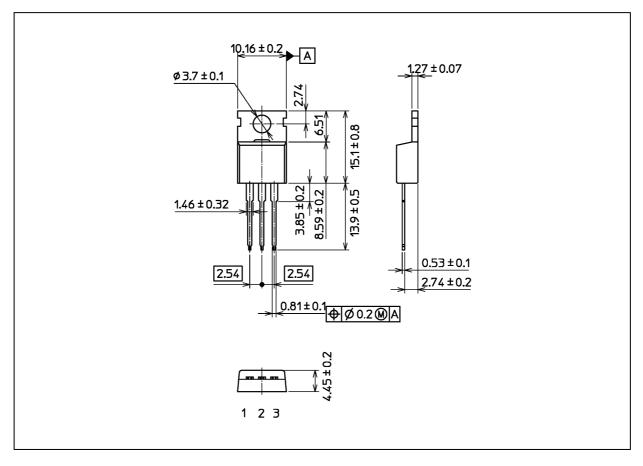
Fig. 8.16 Test Circuit/Waveform

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



Package Dimensions

Unit: mm



Weight: 1.93 g (typ.)

	Package Name(s)
TOSHIBA: 2-10X1A	
Nickname: TO-220	



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